



Features

- **Single Supply Operation:**
+ 2.7V ... + 5.25V
- **Family approach providing**
2 / 4 / 8-Channel Single-Ended or
1 / 2 / 4-Channel Differential Inputs
- **Up to 200ksps Conversion Rate**
- **± 1 LSB INL and DNL**
- **No Missing Codes**
- **> 70 dB SINAD**
- **True fully differential Operation**
- **Software-Configurable Unipolar or Bipolar output coding**
- **Internal 3.2MHz oscillator for independent operation from external clock**
- **Internal 2.5V Reference**
- **Low Power**
 - < 1.2mA (200ksps, 5V supply)
 - < 0.5µA (power-down mode)
- **SPI™ / QSPI™ / MICROWIRE™ - compatible 4-Wire Serial Interface**
- **14 / 16 / 20-Pin SSOP**

Description

The ZADCS12x2 family is a set of low power, 12-bit, successive approximation analog-to-digital (A/D) converters with up to 200ksps conversion rate, two up to eight input channels, high-bandwidth track/hold and synchronous serial interface.

The ADCs operate from a single + 2.7V to + 5.25V supply. Their analog inputs are software configurable for unipolar/bipolar and single-ended/differential operation.

The 4-wire serial interface connects directly to SPI™/ (QSPI™ and MICROWIRE™) devices without external logic.

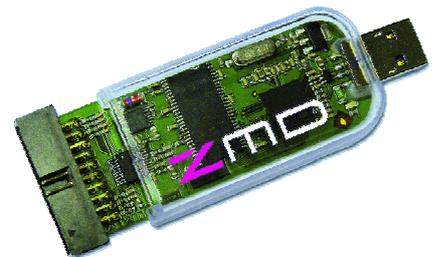
All family devices can use either the external serial-interface clock or an internal clock to perform successive-approximation analog-to-digital conversions. The internal clock can be used to run independent conversions on more than one device in parallel.

The ZADCS12x2V versions are equipped with a highly accurate internal 2.5V reference with an additional external ±1.5% voltage adjustment range.

All members of the ZADCS12x2 family provide a hard-wired shut-down pin (nSHDN) pin and software-selectable power-down modes that can be programmed to automatically shut down the IC at the end of a conversion. Accessing the serial interface automatically powers up the IC. A quick turn-on time allows the device to be shut down between all conversions.

Applications

- Data Acquisition
- Industrial Process Control
- Portable Data Logging
- Battery-Powered Systems



Functional Block Diagram

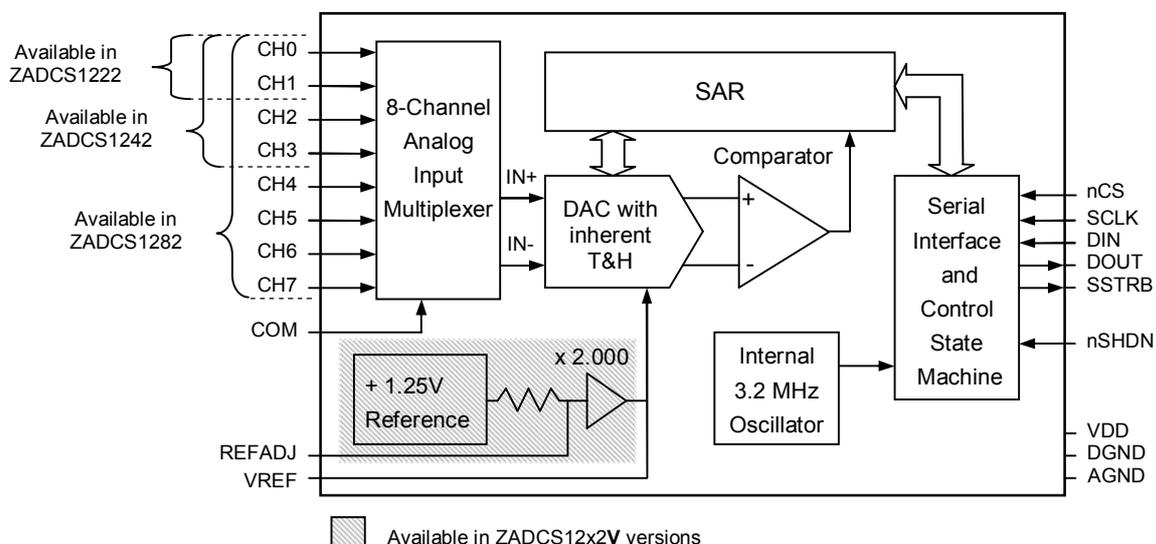


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1 General Device Specification

1.1 Absolute Maximum Ratings (Non Operating)

Table 1: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit	Note
V_{DD-GND}	VDD to AGND, DGND	-0.3	6	V	
$V_{AGND-DGND}$	AGND to DGND	-0.3	0.3	V	
	CH0 – CH7, COM to AGND, DGND	-0.3	VDD+0.3	V	
	VREF, VREFADJ to AGND	-0.3	VDD+0.3	V	
	Digital Inputs to DGND	-0.3	6	V	
	Digital Outputs to DGND	-0.3	VDD+0.3	V	
	Digital Output Sink Current		25	mA	
I_{in}	Input current into any pin except supply pins (Latch-Up)	-100	100	mA	
V_{HBM}	Electrostatic discharge – Human Body Model (HBM)	2000		V	1
θ_{JCT}	Maximum Junction Temperature		+150°	°C	
θ_{OP}	Operating Temperature Range ZADCS12x2VIS20 / ZADCS12x2IS20 ZADCS12x2VQS20 / ZADCS12x2QS20	-25	+85	°C	
		-40	+125	°C	
θ_{STG}	Storage temperature	-65	+150	°C	
θ_{lead}	Lead Temperature 100%Sn	JEDEC-J-STD-20C 260		°C	
H	Humidity non-condensing				2
P_{tot}	Total power dissipation		250	mW	
R_{thj}	Thermal resistance of Package SSOP20 / 5.3mm		100	K/W	

1 HBM: C = 100pF charged to V_{HBM} with resistor R = 1.5k Ω in series, valid for all pins

2 Level 4 according to JEDEC-020A is guaranteed

1.2 Package Pin Assignment ZADCS1282 / ZADCS1282V

Table 2: Pin list

Package pin number	Name	Direction	Type	Description
1	nCS	IN	CMOS Digital	Active Low Chip Select
2	DIN	IN	CMOS Digital	Serial Data Input
3	DGND		SUPPLY	Digital Ground
4	AGND		SUPPLY	Analog Ground
5	VREF	I/O	Analog	Reference Buffer Output / External Reference Input
6	COM	IN	Analog	Ground reference for analog inputs in single ended mode
7	CH0	IN	Analog	Analog Input Channel 0
8	CH1	IN	Analog	Analog Input Channel 1
9	CH4	IN	Analog	Analog Input Channel 4
10	CH5	IN	Analog	Analog Input Channel 5
11	CH7	IN	Analog	Analog Input Channel 7
12	CH6	IN	Analog	Analog Input Channel 6
13	CH3	IN	Analog	Analog Input Channel 3
14	CH2	IN	Analog	Analog Input Channel 2
15	REFADJ	I/O	Analog	Input to Reference Buffer Amplifier
16	VDD		SUPPLY	Positive Supply
17	nSHDN	IN	CMOS Digital	Active Low Shutdown
18	DOUT	OUT	CMOS Digital	Serial Data Output
19	SSTRB	OUT	CMOS Digital	Serial Strobe Output
20	SCLK	IN	CMOS Digital	Serial Clock Input

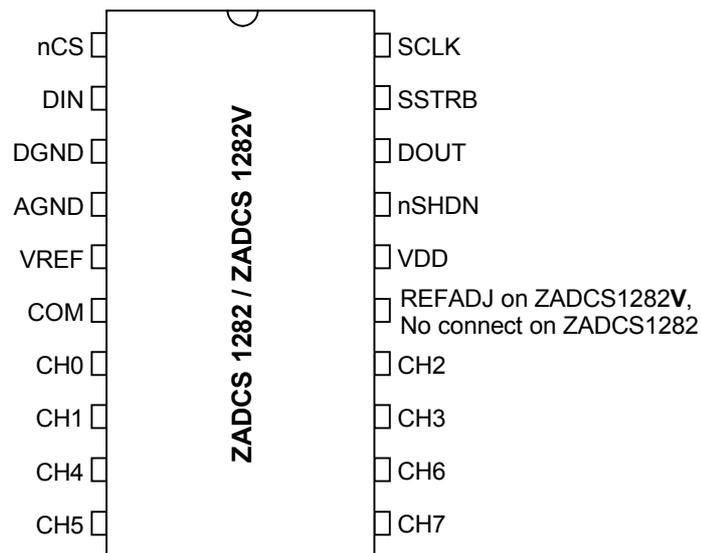


Figure 1: Package Pin Assignment for ZADCS1282 & ZADCS1282V

1.3 Package Pin Assignment ZADCS1242 / ZADCS1242V

Table 3: Pin list

Package pin number	Name	Direction	Type	Description
1	nCS	IN	CMOS Digital	Active Low Chip Select
2	DIN	IN	CMOS Digital	Serial Data Input
3	DGND		SUPPLY	Digital Ground
4	AGND		SUPPLY	Analog Ground
5	VREF	I/O	Analog	Reference Buffer Output / External Reference Input
6	COM	IN	Analog	Ground reference for analog inputs in single ended mode
7	CH0	IN	Analog	Analog Input Channel 0
8	CH1	IN	Analog	Analog Input Channel 1
9	CH3	IN	Analog	Analog Input Channel 3
10	CH2	IN	Analog	Analog Input Channel 2
11	REFADJ	I/O	Analog	Input to Reference Buffer Amplifier
12	VDD		SUPPLY	Positive Supply
13	nSHDN	IN	CMOS Digital	Active Low Shutdown
14	DOUT	OUT	CMOS Digital	Serial Data Output
15	SSTRB	OUT	CMOS Digital	Serial Strobe Output
16	SCLK	IN	CMOS Digital	Serial Clock Input

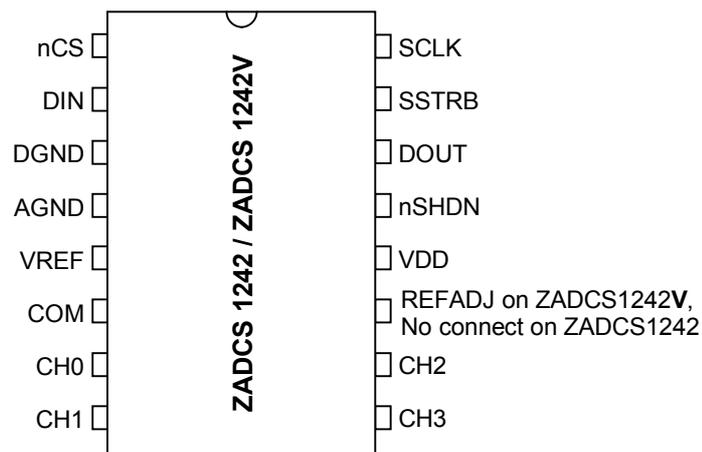


Figure 2: Package Pin Assignment for ZADCS1242 & ZADCS1242V

1.4 Package Pin Assignment ZADCS1222 / ZADCS1222V

Table 4: Pin list

Package pin number	Name	Direction	Type	Description
1	nCS	IN	CMOS Digital	Active Low Chip Select
2	DIN	IN	CMOS Digital	Serial Data Input
3	DGND		SUPPLY	Digital Ground
4	AGND		SUPPLY	Analog Ground
5	VREF	I/O	Analog	Reference Buffer Output / External Reference Input
6	COM	IN	Analog	Ground reference for analog inputs in single ended mode
7	CH0	IN	Analog	Analog Input Channel 0
8	CH1	IN	Analog	Analog Input Channel 1
9	REFADJ	I/O	Analog	Input to Reference Buffer Amplifier
10	VDD		SUPPLY	Positive Supply
11	nSHDN	IN	CMOS Digital	Active Low Shutdown
12	DOUT	OUT	CMOS Digital	Serial Data Output
13	SSTRB	OUT	CMOS Digital	Serial Strobe Output
14	SCLK	IN	CMOS Digital	Serial Clock Input

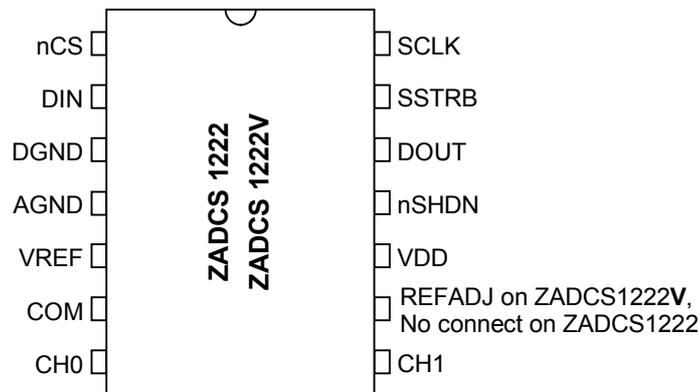


Figure 3: Package Pin Assignment for ZADCS1222 & ZADCS1222V

1.5 Electrical Characteristics

1.5.1 General Parameters

(VDD = +2.7V to + 5.25V; f_{SCLK} = 3.2MHz (50% duty cycle); 16 clocks/conversion cycle (200 ksps); V_{REF} = 2.500V applied to VREF pin; $\theta_{OP} = \theta_{OPmin} \dots \theta_{OPmax}$)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
DC Accuracy						
Resolution				12		Bits
Relative Accuracy		ZADCS1282 / ZADCS1282V ZADCS1242 / ZADCS1242V ZADCS1222 / ZADCS1222V			± 1.0	LSB
No Missing Codes	NMC		12			Bits
Differential Nonlinearity		ZADCS1282 / ZADCS1282V ZADCS1242 / ZADCS1242V ZADCS1222 / ZADCS1222V			± 1.0	LSB
Offset Error				± 0.5	± 3.0	LSB
Gain Error				± 0.5	± 4.0	LSB
Gain Temperature Coefficient				± 0.25		ppm/°C
Dynamic Specifications (10kHz sine-wave input, 0V to 2.500Vpp, 200ksps, 3.2MHz external clock)						
Signal-to-Noise + Distortion Ratio	SINAD		70	73		dB
Total Harmonic Distortion	THD	Up to the 5 th harmonic		-88	-80	dB
Spurious-Free Dynamic Range	SFDR		76	80		dB
Small-Signal Bandwidth		-3dB roll off		3.8		MHz
Conversion Rate						
Sampling Time (= Track/Hold Acquisition Time)	t _{ACQ}	Ext. Clock = 3.2MHz, 2.5 clocks/ acquisition	0.781			µs
Conversion Time	t _{CONV}	Ext. Clock = 3.2MHz, 12 clocks/ conversion			3.75	µs
		Int. Clock = 3.2MHz +/- 12% tolerance	3.30		4.20	µs
Aperture Delay				30		ns
Aperture Jitter				< 50		ps
External Clock Frequency			0.1		3.2	MHz
Internal Clock Frequency			2.81	3.2	3.58	MHz
Analog Inputs						
Input Voltage Range, Single-Ended and Differential		Unipolar, COM = 0V	0 to VREF			V
		Bipolar, COM = VREF/2	± VREF / 2			
Input Capacitance			16			pF

1.5.2 Specific Parameters of versions with Internal Voltage Reference (ZADCS12x2V)

(VDD = +2.7V to + 5.25V; f_{SCLK} = 3.2MHz (50% duty cycle); 16 clocks/conversion cycle (200 ksps); θ_{OP} = θ_{OPmin} ... θ_{OPmax})

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Internal Reference at VREF						
VREF Output Voltage		T _A = + 25°C	2.480	2.500	2.520	V
VREF Short-Circuit Current					30	mA
VREF Temperature Coefficient				± 20	± 30	ppm/°C
Load Regulation		0 to 0.2mA output load		0.35		mV
Capacitive Bypass at VREF			4.7			µF
Capacitive Bypass at REFADJ			0.047			µF
REFADJ Adjustment Range				± 1.5		%
External Reference at VREF (internal buffer disabled by V(REFADJ) = VDD)						
VREF Input Voltage Range			1.0		VDD + 50mV	V
VREF Input Current		VREF = 2.5V		180	215	µA
VREF Input Resistance			11.5	14		kΩ
Shutdown VREF Input Current					0.1	µA
REFADJ Buffer Disable Threshold			VDD-0.5			V
External Reference at VREF_ADJ						
Reference Buffer Gain				2.00		
VREF_ADJ Input Current					±80	µA
Full Power Down VREFADJ Input Current		Full Power-Down mode			0.1	µA
Power Requirements						
Positive Supply Voltage	VDD		2.7		5.25	V
Positive Supply Current ZADCS1282VI ZADCS1242VI ZADCS1222VI	IDD	VDD=3.6V	Operating Mode ext. VREF	0.85	1.0	mA
			Operating Mode int. VREF	1.3	1.4	mA
			Fast Power-Down	250	300	µA
			Full Power-Down	0.5	4.0	µA
Positive Supply Current ZADCS1282VI ZADCS1242VI ZADCS1222VI	IDD	VDD=5.2V	Operating Mode ext. VREF	1.00	1.3	mA
			Operating Mode int. VREF	1.40	1.6	mA
			Fast Power-Down	250	300	µA
			Full Power-Down	0.5	4.0	µA
Positive Supply Current ZADCS1282VQ ZADCS1242VQ ZADCS1222VQ	IDD	VDD=3.6V	Operating Mode ext. VREF	0.85	1.1 ¹⁾	mA
			Operating Mode int. VREF	1.3	1.5 ¹⁾	mA
			Fast Power-Down	250	350 ¹⁾	µA
			Full Power-Down	0.5	15 ¹⁾	µA
Positive Supply Current ZADCS1282VQ ZADCS1242VQ ZADCS1222VQ	IDD	VDD=5.2V	Operating Mode ext. VREF	1.00	1.4 ¹⁾	mA
			Operating Mode int. VREF	1.40	1.7 ¹⁾	mA
			Fast Power-Down	250	350 ¹⁾	µA
			Full Power-Down	0.5	20 ¹⁾	µA

¹⁾ relaxed maximum limits are due to wider temperature range of automotive qualified version ZADCS12x2VQ

1.5.3 Specific Parameters of versions without Internal Voltage Reference (ZADCS12x2)

(VDD = +2.7V to + 5.25V; f_{SCLK} = 3.2MHz (50% duty cycle); 16 clocks/conversion cycle (200 ksps); $\theta_{OP} = \theta_{OPmin} \dots \theta_{OPmax}$)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
External Reference at VREF						
VREF Input Voltage Range			1.0		VDD + 50mV	V
VREF Input Current		VREF = 2.5V		180	215	µA
VREF Input Resistance			11.5	14		kΩ
Shutdown VREF Input Current					0.1	µA
Capacitive Bypass at VREF			4.7			µF
Power Requirements						
Positive Supply Voltage	VDD		2.7		5.25	V
Positive Supply Current ZADCS1282I, ZADCS1242I, ZADCS1222I	IDD	VDD = 3.6V	Operating Mode	0.85	1.0	µA
			Full Power-Down	0.5	4.0	
Positive Supply Current ZADCS1282I, ZADCS1242I, ZADCS1222I	IDD	VDD = 5.25V	Operating Mode	1.00	1.3	µA
			Full Power-Down	0.5	4.0	
Positive Supply Current ZADCS1282Q, ZADCS1242Q, ZADCS1222Q	IDD	VDD = 3.6V	Operating Mode	0.85	1.0 ¹⁾	µA
			Full Power-Down	0.5	15 ¹⁾	
Positive Supply Current ZADCS1282Q, ZADCS1242Q, ZADCS1222Q	IDD	VDD = 5.25V	Operating Mode	1.00	1.3 ¹⁾	µA
			Full Power-Down	0.5	20 ¹⁾	

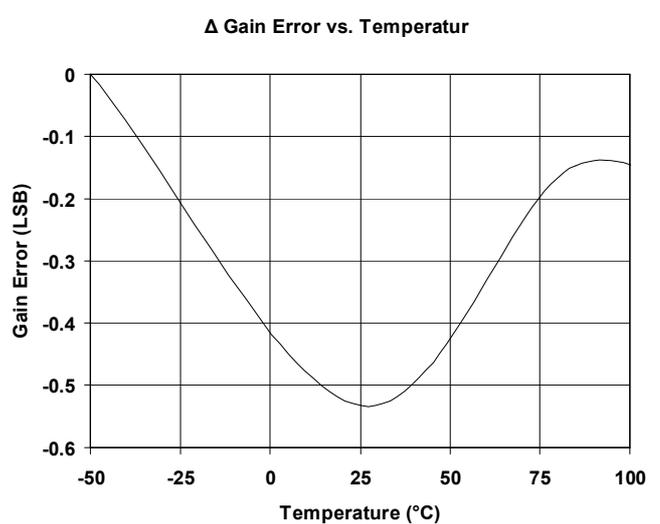
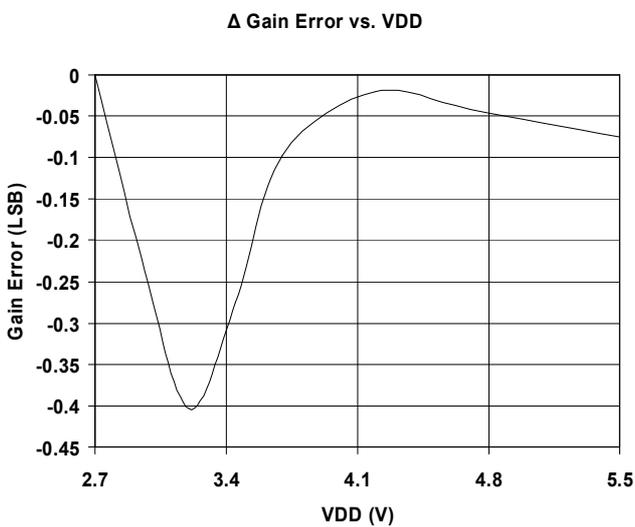
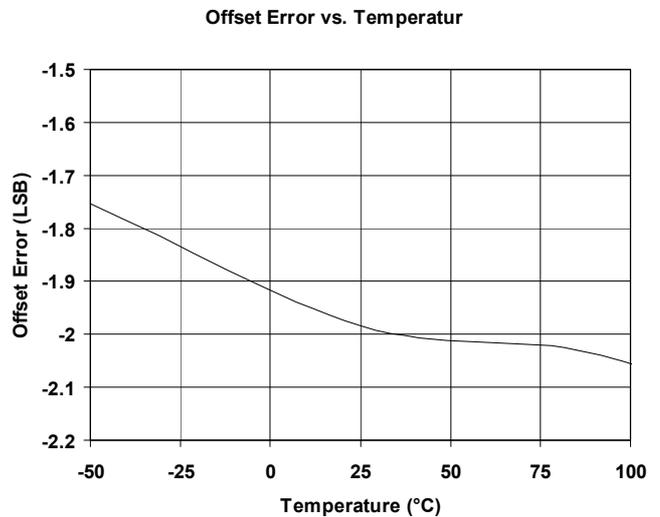
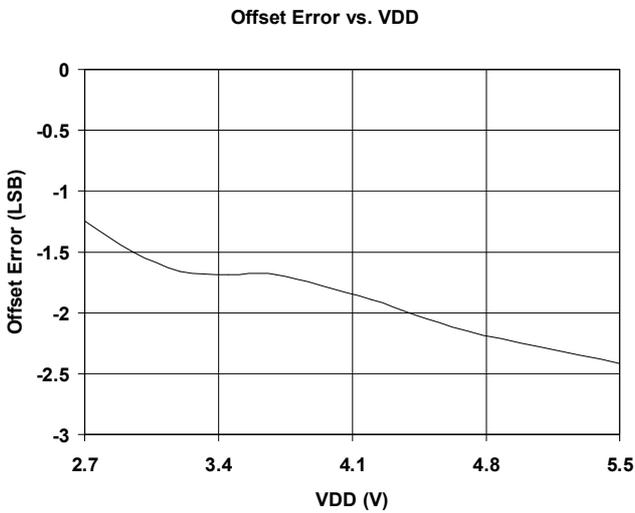
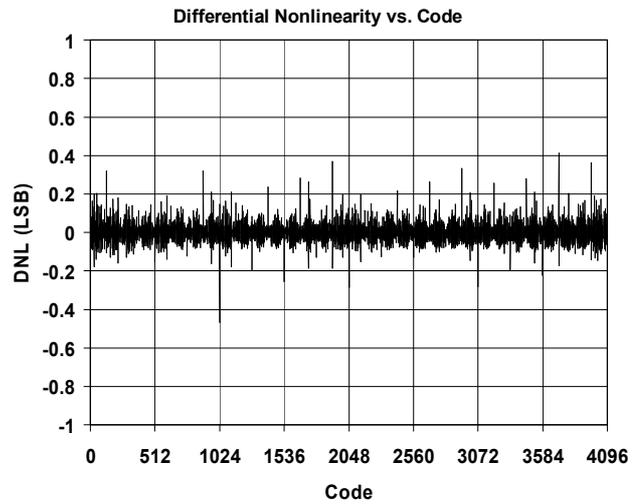
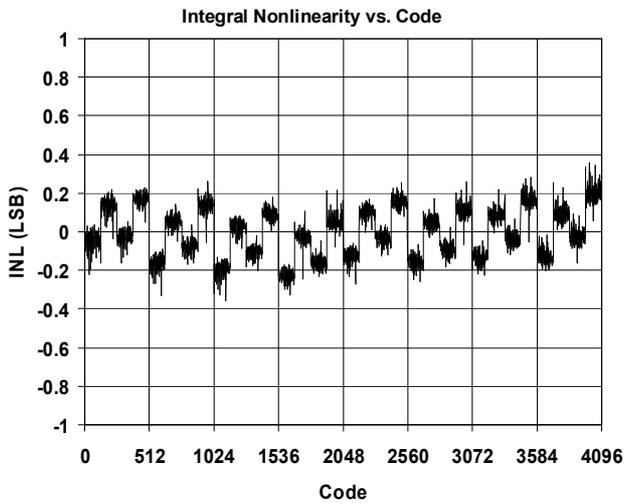
¹⁾ relaxed maximum limits are due to wider temperature range of automotive qualified version ZADCS12x2Q

1.5.4 Digital Pin Parameters

(VDD = +2.7V to + 5.25V; f_{SCLK} = 3.2MHz (50% duty cycle); 16 clocks/conversion cycle (200 ksps); $\theta_{OP} = \theta_{OPmin} \dots \theta_{OPmax}$)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Digital Inputs (DIN, SCLK, CS, nSHDN)						
Logic High Level	V _{IH}	VDD = 2.7V	1.9			V
		VDD = 5.25V	3.3			V
Logic Low Level	V _{IL}	VDD = 2.7V			0.7	V
		VDD = 5.25V			1.4	V
Hysteresis	V _{Hyst}		0.7			V
Input Leakage	I _{IN}	VIN = 0V or VDD		± 0.1	± 1.0	µA
Input Capacitance	C _{IN}			5		pF
Digital Output (DOUT, SSTRB)						
Output High Current	I _{OH}	V _{OH} = VDD – 0.5V	VDD = 2.7V	3.5	8.5	mA
			VDD = 5.25V	5.5	10.8	mA
Output Low Voltage	I _{OL}	V _{OL} = 0.4V	VDD = 2.7V	4	11.5	mA
			VDD = 5.25V	6.4	15.3	mA
Three-State Leakage Current	I _{Leak}	nCS = VDD		± 0.1	± 1.0	µA
Three-State Output Capacitance	C _{OUT}	nCS = VDD		5		pF

1.6 Typical Operating Characteristics



(VDD = +5.0V; $f_{\text{Sample}} = 200\text{kHz}$, $f_{\text{CLK}} = 16 \cdot f_{\text{Sample}} = 3.2\text{MHz}$; VREF = 2.500V applied to VREF pin; $\theta_{\text{OP}} = +25^\circ\text{C}$)

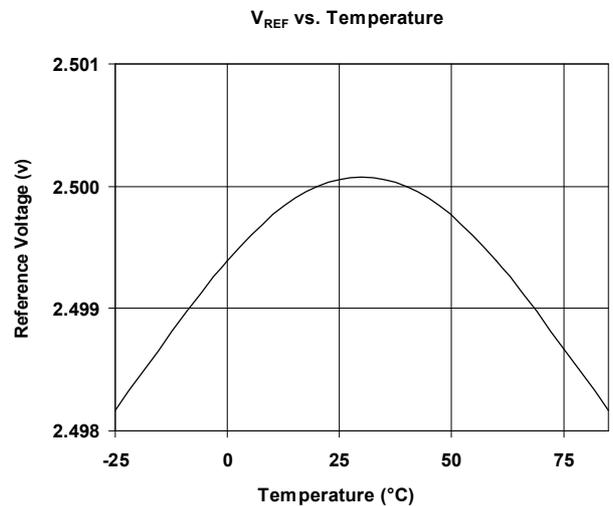
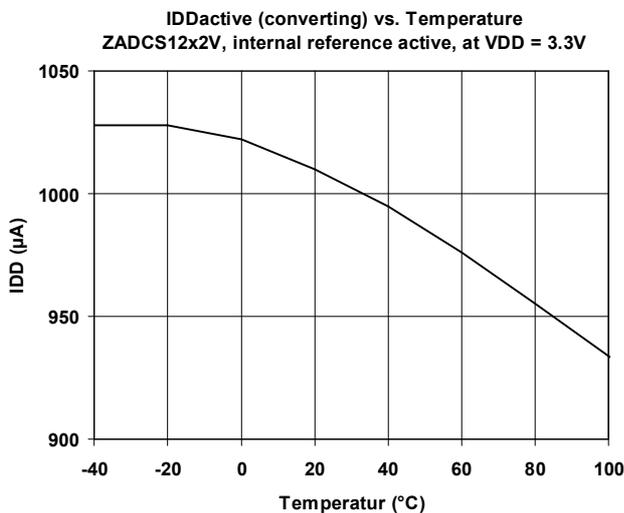
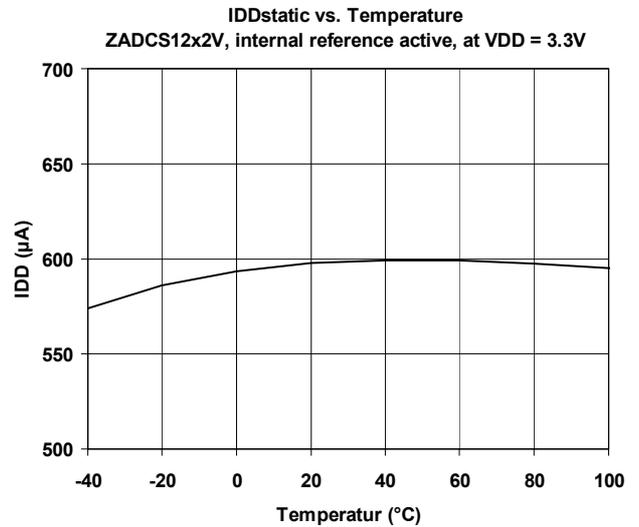
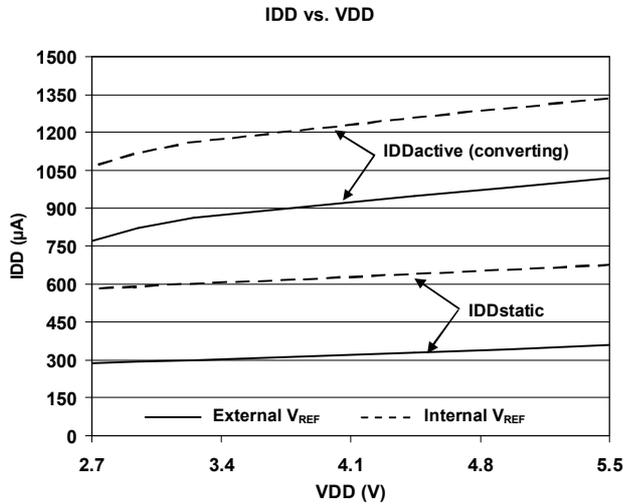
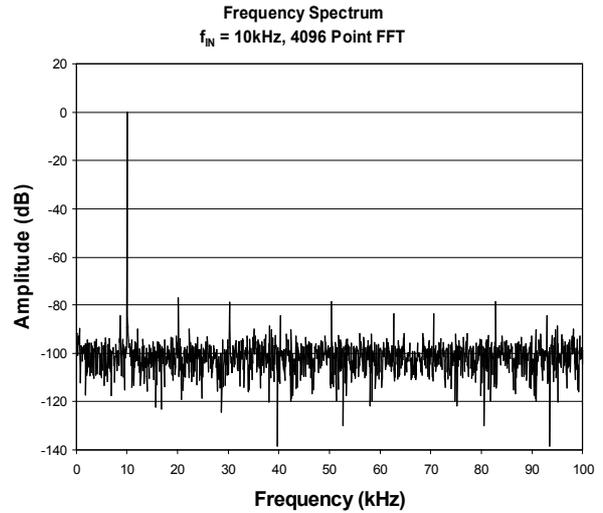
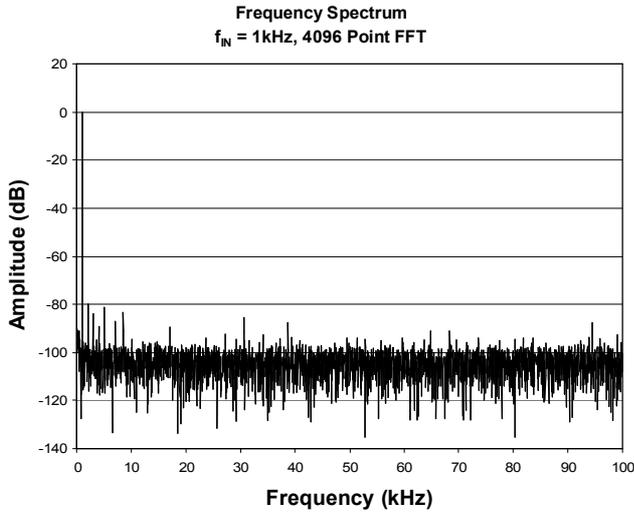
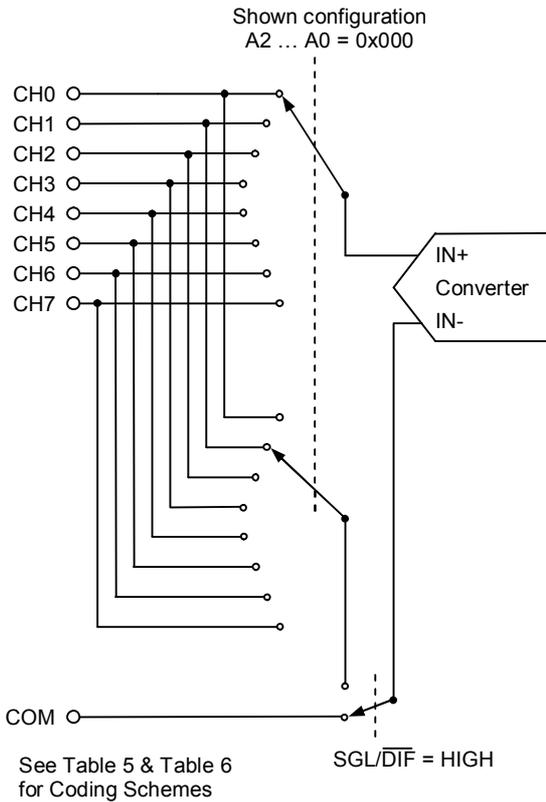


Figure 7: Block diagram of input multiplexer



In unipolar mode the voltage at IN_+ must exceed the voltage at IN_- to obtain codes unequal to $0x000$. The entire 12 bit transfer characteristic is then covered by IN_+ if IN_+ ranges from IN_- to $(IN_- + V_{REF})$. Any voltage on IN_+ > $(IN_- + V_{REF})$ results in code $0xFFFF$. Code $0xFFFF$ is not reached, if $(IN_- + V_{REF}) > V_{DD} + 0.2V$ because the input voltage is clamped at $V_{DD} + 0.2V$ by ESD protection devices.

The voltage at IN_- can range from $-0.2V \dots \frac{1}{2} V_{REF}$ without limiting the Code Range, assuming the fore mentioned V_{DD} condition is true. See also Figure 8 for input voltage ranges in unipolar conversion mode.

In bipolar mode, IN_+ can range from $(IN_- - V_{REF}/2)$ to $(IN_- + V_{REF}/2)$ keeping the converter out of code saturation. For instance, if IN_- is set to a constant DC voltage of $V_{REF}/2$, then IN_+ can vary from $0V$ to V_{REF} to cover the entire code range. Lower or higher voltages of IN_+ keep the output code at the minimum or maximum code value.

Figure 9 shows the input voltage ranges in bipolar mode when IN_- is set to a constant DC voltage.

As explained before, converters out of the ZADCS12x2 family can also be used to convert fully differential input signals that change around a common mode input voltage.

The bipolar mode is best used for such purposes since it allows the input signals to be positive or negative in relation to each other.

The common mode level of a differential input signal is calculated $V_{CM} = (V(IN_+) + V(IN_-)) / 2$. To avoid code clip-

Figure 8: Input voltage range in unipolar mode

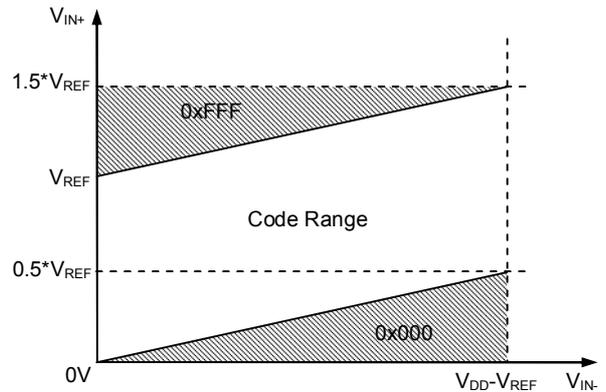
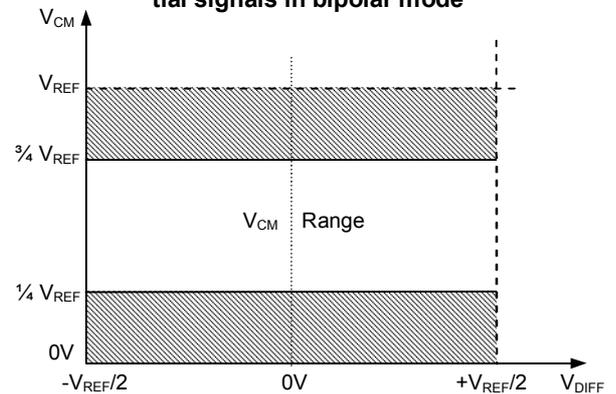


Figure 9: Input voltage range for fully differential signals in bipolar mode



ping or over steering of the converter, the common mode level can change from $\frac{1}{4} V_{REF} \dots \frac{3}{4} V_{REF}$. Within this range the peak to peak amplitude of the differential input signal can be $\pm V_{REF}/2$.

The average input current on the analog inputs depends on the conversion rate. The signal source must be capable of charging the internal sampling capacitors (typically 16pF on each input of the converter: IN_+ and IN_-) within the acquisition time t_{ACQ} to the required accuracy. The equivalent input circuit in sampling mode is shown in Figure 6.

The following equation provides a rough hand calculation for a source impedance R_S that is required to settle out a DC input signal referenced to AGND with 12 bit accuracy in a given acquisition time

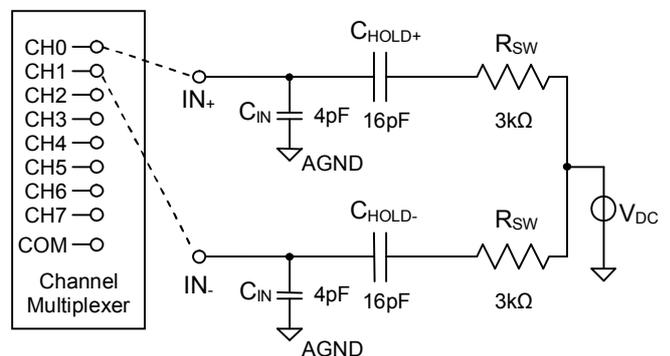


Figure 6: Equivalent input circuit during sampling

$$R_S \leq \frac{t_{ACQ}}{9 \times C_{IN}} - R_{SW}$$

For example, if $f_{SCLK} = 3.2\text{MHz}$, the acquisition time is $t_{ACQ} = 781.25\text{ns}$. Thus the output impedance of the signal source R_S must be less than

$$R_S \leq \frac{781.25\text{ns}}{9 \times 20\text{pF}} - 3\text{k}\Omega = 1.34\text{k}\Omega$$

If the output impedance of the source is higher than the calculated maximum R_S the acquisition time must be extended by reducing f_{SCLK} to ensure 12 bit accuracy. Another option is to add a capacitor of $>20\text{ nF}$ to the individual input. Although this limits the bandwidth of the input signal because an RC low pass filter is built together with the source impedance, it may be useful for certain applications.

The small-signal bandwidth of the input tracking circuitry is 3.8 MHz. Hence it is possible to digitize high-speed transient events and periodic signals with frequencies exceeding the ADC's sampling rate. This allows the application of certain under-sampling techniques like down conversion of modulated high frequency signals.

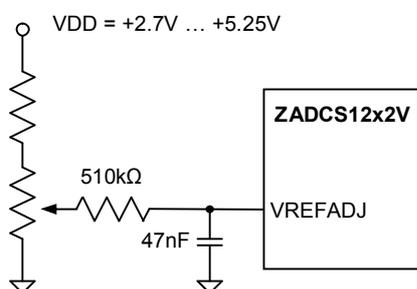
Be aware that under-sampling techniques still require a bandwidth limitation of the input signal to less than the Nyquist frequency of the converter to avoid aliasing effects. Also, the output impedance of the input source must be very low to achieve the mentioned small signal bandwidth in the overall system.

2.3 Internal & External Reference

ZADCS12x2V family members are equipped with a highly accurate internal 2.5V reference voltage source. The voltage is generated from a trimmed 1.25V bandgap with an internal buffer that is set to a gain of 2.00. The bandgap voltage is supplied at VREFADJ with an output impedance of 20kΩ. An external capacitor of 47nF at VREFADJ is useful to further decrease noise on the internal reference.

The VREFADJ pin also provides an opportunity to externally adjust the bandgap voltage in a limited range (see Figure 10) as well as the possibility to overdrive the internal bandgap with an external 1.25V reference.

Figure 10: Reference Adjust Circuit



The internal bandgap reference and the VREF buffer can be shut down completely by setting VREFADJ to VDD. This reduces power consumption of the ZADCS12x2V

devices and allows the supply of an external reference at VREF.

Basic ZADCS12x2 devices do not contain the internal bandgap or the VREF buffer. An external reference must be supplied all the time at VREF.

The value of the reference voltage at VREF sets the input range of the converter and the analog voltage weight of each digital code. The size of the LSB (least significant bit) is equal to the value of VREF (reference to AGND) divided by 4096. For example at a reference voltage of 2.500V, the voltage level of a LSB is equal to 610μV.

It is important to know that certain inherent errors in the A/D converter, like offset or gain error, will appear to increase at lower reference voltages while the actual performance of the device does not change. For instance a static offset error of 1.22mV is equal to 2 LSB at 2.5V reference, while it is equivalent to 5.0 LSB for a reference voltage of 1.0V

Likewise, the uncertainty of the digitized output code will increase with lower LSB size (lower VREF). Once the size of an LSB is below the internal noise level, the output code will start to vary around a mean value for constant DC input voltages. Such noise can be reduced by averaging consecutive conversions or applying a digital filter.

The average current consumption at VREF depends on the value of VREF and the sampling frequency. Two effects contribute to the current at VREF, a resistive connection from VREF to AGND and charge currents that result from the switching and recharging of the capacitor array (CDAC) during sampling and conversion.

For an external reference of 2.5V the input current at VREF is approximately 100μA.

2.4 Digital Interface

All devices out of the ZADCS12x2 family are controlled by a 4-wire serial interface that is compatible to SPI™, QSPI™ and MICROWIRE™ devices without external logic.

Any conversion is started by sending a control byte into DIN while nCS is low. A typical sequence is shown in Figure 11.

The control byte defines the input channel(s), unipolar or bipolar operation and output coding, single-ended or differential input configuration, external or internal conversion clock and the kind of power down that is activated after the completion of a conversion. A detailed description of the control bits can be obtained from Table 7.

As it can also be seen in Figure 11 the acquisition of the input signal occurs at the end of the control byte for 2.5 clock cycles. Outside this range, the Track & Hold is in hold mode.

The conversion process is started, with the falling clock edge (SCLK) of the eighth bit in the control byte. It takes twelve clock cycles to complete the conversion and one additional cycle to shift out the last bit of the conversion result. During the remaining three clock cycles the output is filled with zeros in 24-Clock Conversion Mode.

Depending on what clock mode was selected, either the external SPI clock or an internal clock is used to drive the successive approximation. Figure 12 shows the Timing for Internal Clock Mode.

Figure 11: 24-Clock External Clock Mode Timing (SPI™, QSPI™ and MICROWIRE™ compatible, $f_{SCLK} \leq 3.2\text{MHz}$)

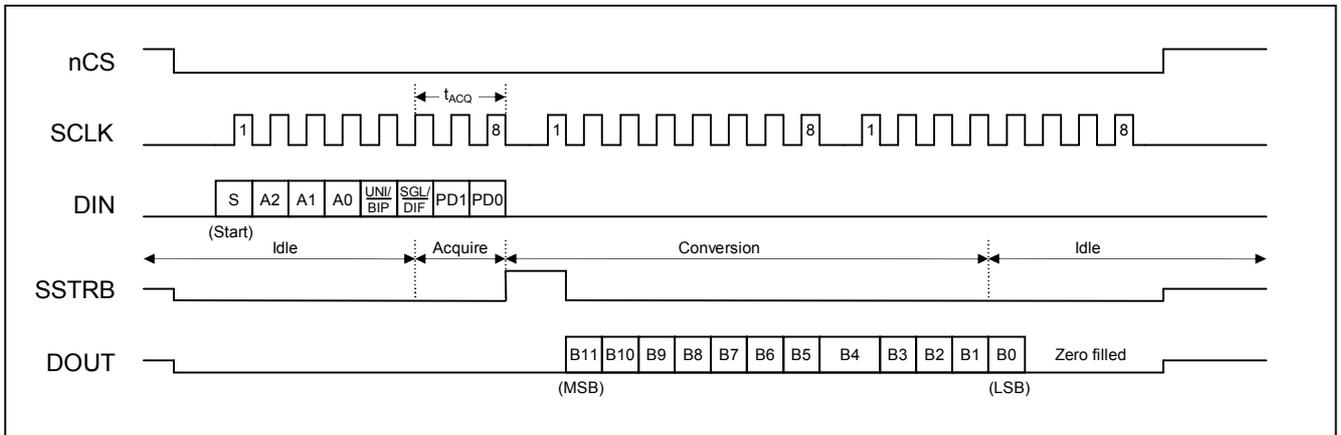


Figure 12: Internal Clock Mode Timing with interleaved Control Byte transmission

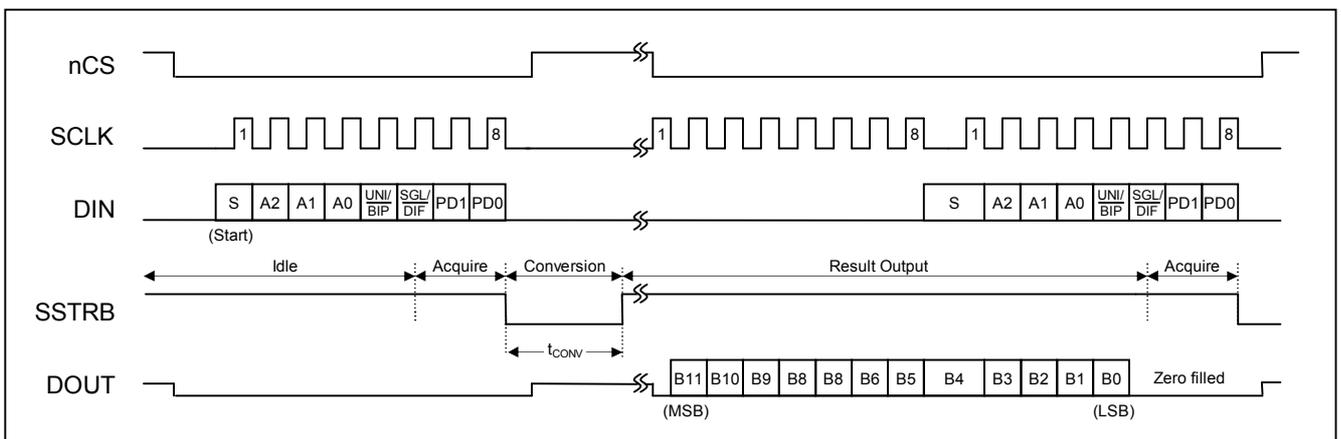


Table 7: Control Byte Format

BIT	Name	Description															
7 (MSB)	START	The Start Bit is defined by the first logic '1' after nCS goes low.															
6 5 4	A2 A1 A0	Channel Select Bits. Along with SGL/DIF these bits control the setting of the input multiplexer. For further details on the decoding see also Table 5 and Table 6.															
3	UNI/BIP	Output Code Select Bit. The value of the bit determines conversion mode and output code format. '1' = unipolar - straight binary coding '0' = bipolar - two's complement coding															
2	SGL/DIF	Single-Ended / Differential Select Bit. Along with the Channel Select Bits A2 .. A0 this bit controls the setting of the input multiplexer '1' = single ended - all channels CH0 ... CH7 measured referenced to COM '0' = differential - the voltage between two channels is measured															
1 0 (LSB)	PD1 PD0	Power Down and Clock Mode Select Bits <table border="1" style="display: inline-table; vertical-align: top;"> <thead> <tr> <th>PD1</th> <th>PD0</th> <th>Mode</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>Full Power-Down</td> </tr> <tr> <td>0</td> <td>1</td> <td>Fast Power-Down</td> </tr> <tr> <td>1</td> <td>0</td> <td>Internal clock mode</td> </tr> <tr> <td>1</td> <td>1</td> <td>External clock mode</td> </tr> </tbody> </table>	PD1	PD0	Mode	0	0	Full Power-Down	0	1	Fast Power-Down	1	0	Internal clock mode	1	1	External clock mode
PD1	PD0	Mode															
0	0	Full Power-Down															
0	1	Fast Power-Down															
1	0	Internal clock mode															
1	1	External clock mode															

Figure 13: 16-Clock External Clock Mode Conversion

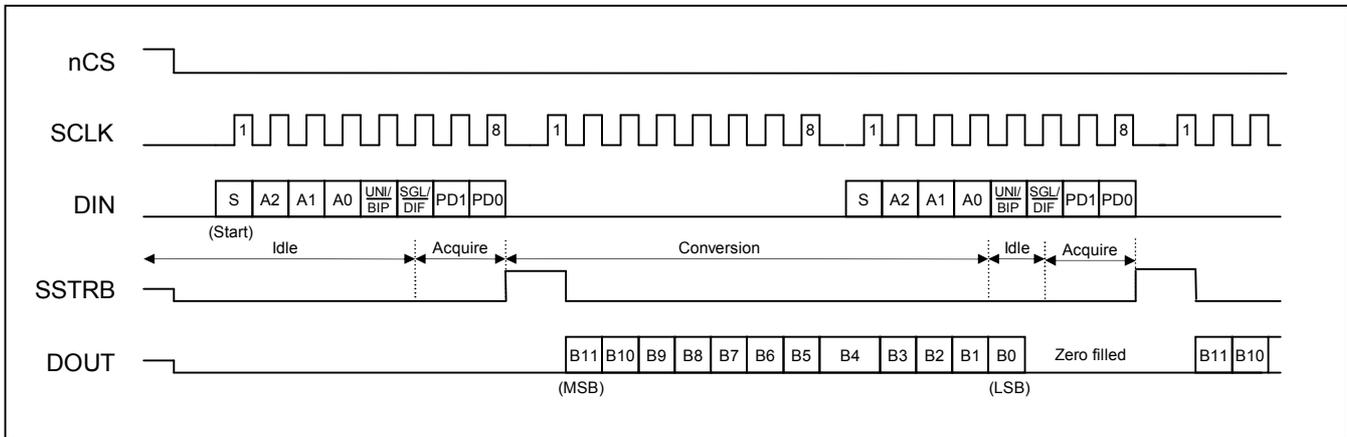
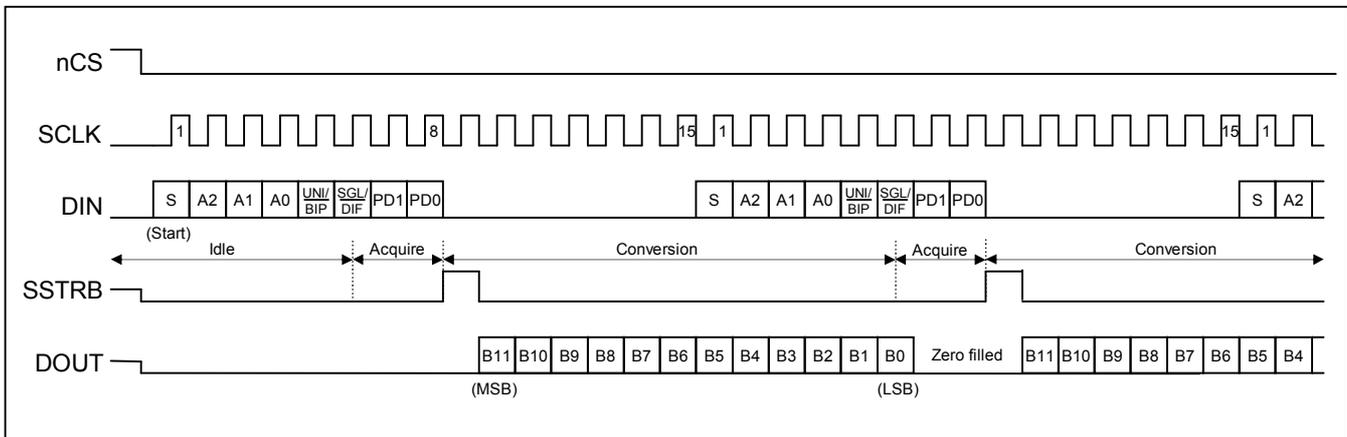


Figure 14: 15-Clock External Clock Mode Conversion



Internal Clock Mode

In Internal Clock Mode, the conversion starts at the falling clock edge of the eighth control bit just as in External Clock Mode. However, there are no further clock pulses required at SCLK to complete the conversion. The conversion clock is generated by an internal oscillator that runs at approximately 3.2MHz. While the conversion is running, the SSTRB signal is driven LOW. As soon as the conversion is complete, SSTRB is switched to HIGH, signaling that the conversion result can be read out on the serial interface.

To shorten cycle times ZADCS12x2 family devices allow interleaving of the read out process with the transmission of a new control byte. Thus it is possible to read the conversion result and to start a new conversion with just two consecutive byte transfers, instead of three bytes that would have to be sent without the interleaving function.

While the IC is performing a conversion in Internal Clock Mode, the Chip Select signal (nCS) may be tied HIGH allowing other devices to communicate on the bus. The output driver at DOUT is switched into a high impedance state while nCS is HIGH. The conversion time t_{CONV} may vary in the specified limits depending on the actual VDD and temperature values.

16-Clocks per Conversion

Interleaving of the data read out process and transmission of a new Control Byte is also supported for External Clock Mode operation. Figure 13 shows the transmission timing for conversion runs using 16 clock cycles per run. In fact, the specified converter sampling rate of 200ksps will be reached in this mode, provided the clock frequency is set to 3.2MHz.

15-Clocks per Conversion

ZADCS12x2 family devices do also support a 15 clock cycle conversion mode (see Figure 14). This is the fastest conversion mode possible. Usually micro controllers do not support this kind of 15 bit serial communication transfers. However, specifically designed digital state machines implemented in Field Programmable Gate Arrays (FPGA) or Application Specific Integrated Circuits (ASIC) may use this operation mode. Applications that utilize the 15 clock cycle conversion mode gain an increase in sampling rate to 213.3ksps keeping the clock frequency unchanged at 3.2MHz.

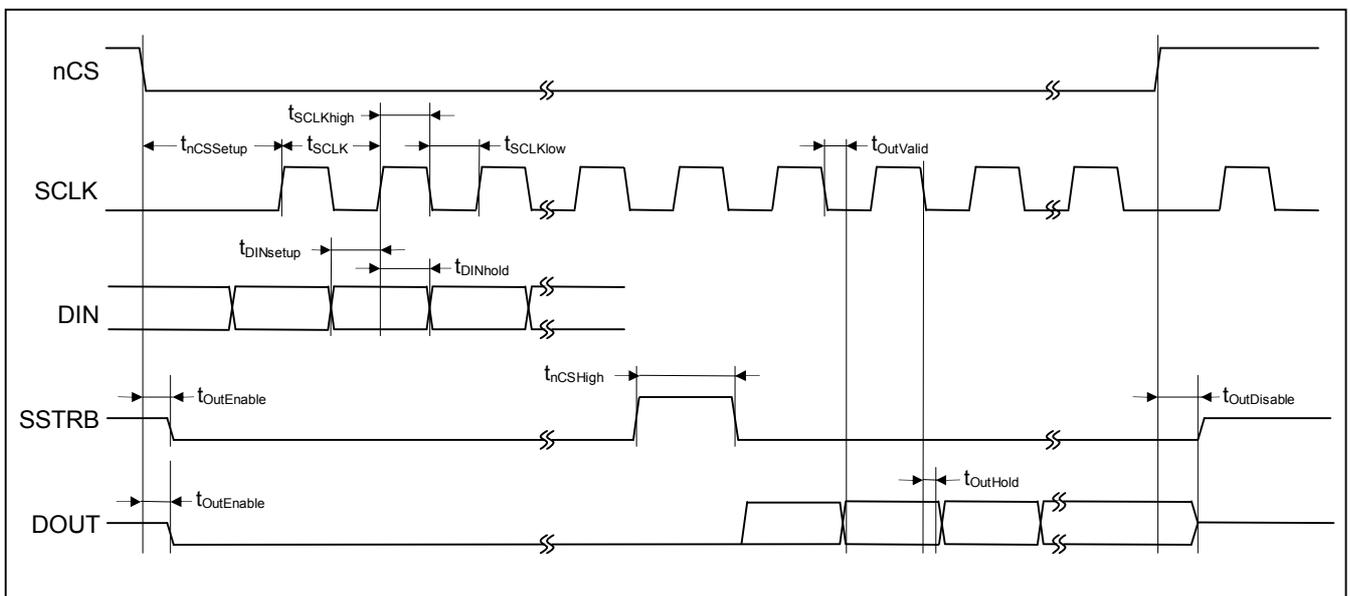
Digital Timing

In general the clock frequency at SCLK may vary from 0.1MHz to 3.2MHz. Considering all telegram pauses or other interruptions of a continuous clock at SCLK, each conversion must be completed within 1.2ms from the

Table 8: Timing Characteristics (VDD = +2.7V to + 5.25V; $\theta_{OP} = \theta_{OPmin} \dots \theta_{OPmax}$)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
SCLK Periode	t_{SCLK}		312.50			ns
SCLK Pulse Width High	$t_{SCLKhigh}$		156.25			ns
SCLK Pulse Width Low	$t_{SCLKlow}$		156.25			ns
DIN to SCLK Setup	$t_{DinSetup}$		30			ns
DIN to SCLK Hold	$t_{DinHold}$		10			ns
nCS Fall to SCLK Setup	$t_{nCSSetup}$		30			ns
SCLK Fall to DOUT & SSTRB Hold	$t_{OutHold}$	$C_{Load} = 20pF$	10			ns
SCLK Fall to DOUT & SSTRB Valid	$t_{OutValid}$	$C_{Load} = 20pF$			40	ns
nCS Rise to DOUT & SSTRB Disable	$t_{OutDisable}$	$C_{Load} = 20pF$	10		60	ns
nCS Fall to DOUT & SSTRB Enable	$t_{OutEnable}$	$C_{Load} = 20pF$			60	ns
nCS Pulse Width High	$t_{nCSHigh}$		100			ns

Figure 15: Detailed Timing Diagram



falling clock edge of the eighth bit in the Control Byte. Otherwise the signal that was captured during sample/hold may drop to noticeable affect the conversion result.

Further detailed timing information on the digital interface is provided in Table 8 and Figure 15.

Output Code Format

ZADCS12x2 family devices do all support unipolar and bipolar operation modes. The digital output code is straight binary in unipolar mode. It ranges from 0x000 for an input voltage difference of 0V to 0xFFF for an input

voltage difference of V_{REF} (Full Scale = FS). The first code transition (0x000 → 0x001) occurs at a voltage equivalent to $\frac{1}{2}$ LSB, the last (0xFFE → 0xFFF) at $V_{REF} - 1.5$ LSB. See also Figure 16 for details.

In bipolar mode a two's complement coding is applied. Code transitions occur again halfway between successive integer LSB values. The transfer function is shown in Figure 17.

Figure 16: Unipolar Transfer Function

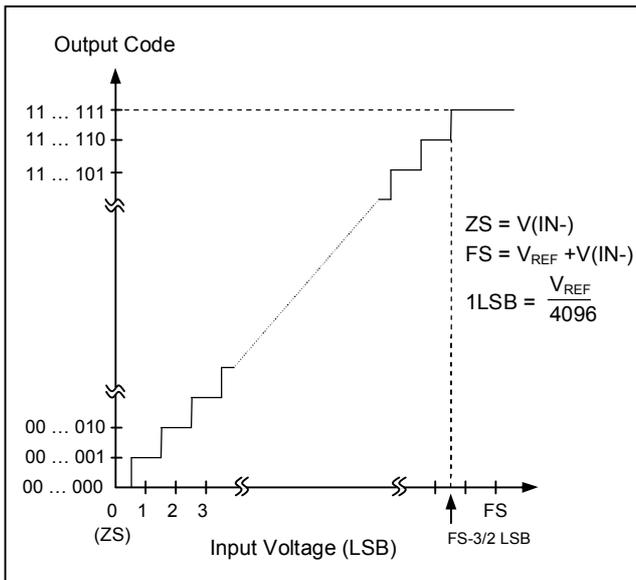
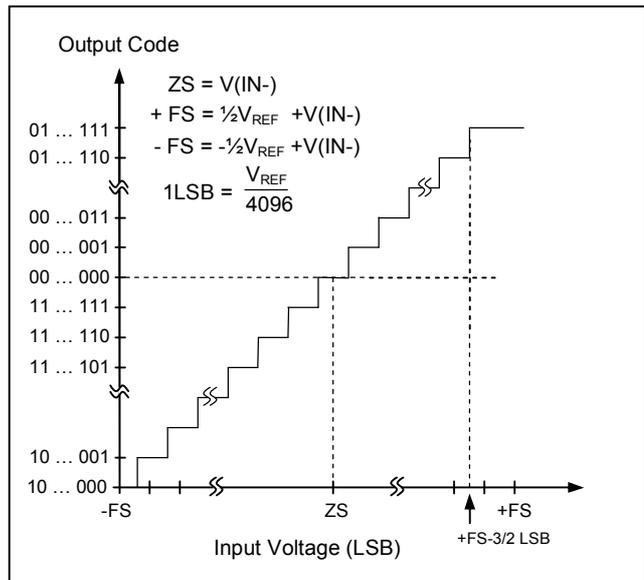


Figure 17: Bipolar Transfer Function



2.5 Power Dissipation

The ZADCS12x2 family offers three different ways to save operating current between conversions. Two different software controlled power down modes can be activated to automatically shut-down the device after completion of a conversion. They differ in the amount of circuitry that is powered down.

Software Power Down

Full Power Down Mode shuts down the entire analog part of the IC, reducing the static I_{DD} of the device to less than $0.5\mu A$ if no external clock is provided at SCLK.

Fast Power Down mode is only useful with ZADCS12x2V devices if the internal voltage reference is used. During Fast Power-Down the bandgap and the VREFADJ output buffer are kept alive while all other internal analog circuitry is shut down. The benefit of Fast Power Down mode is a shorter turn on time of the reference compared to Full Power-Down Mode. This is basically due to the fact that the low pass which is formed at the VREFADJ output by the internal $20k\Omega$ resistor and the external buffer capacitor of $47nF$ is not discharged in Fast Power-Down Mode.

The settling time of the low pass at VREFADJ is about 9 ms to reach 12 bit accuracy. The Fast Power Down mode omits this settling and reduces the turn on time to about $200\mu s$.

To wake up the IC out of either software power down mode, it is sufficient to send a Start Bit while nCS is LOW. Since micro controllers can commonly transfer full bytes per transaction only, a dummy conversion is usually carried out to wake the device.

In all application cases where an external reference voltage is supplied (basic ZADCS12x2 and ZADCS12x2V with VREFADJ tied to VDD) there is no turn on time to be considered. The first conversion is already valid. Fast Power-Down and Full Power-Down Mode do not show any difference in this configuration.

Hardware Power Down

The third power down mode is called Hardware Power-Down. It is initiated by pulling the nSHDN pin LOW. If this condition is true, the device will immediately shut down all circuitry just as in Full Power Down-Mode.

The IC wakes up if nSHDN is tied HIGH. There is no internal pull-up that would allow nSHDN to float during normal operation. This ensures the lowest possible power consumption in power down mode.

General Power Considerations

Even without activating any power down mode, the devices out of the ZADCS12x2 family reduce their power consumption between conversions automatically. The comparator, which contributes a considerable amount to the overall current consumption of the device, is shut off as soon as a conversion is ended. It gets turned on at the start of the next acquisition period. This explains the difference between the $I_{DDstatic}$ and $I_{DDactive}$ measurements shown in chapter 1.6 Typical Operating Characteristics.

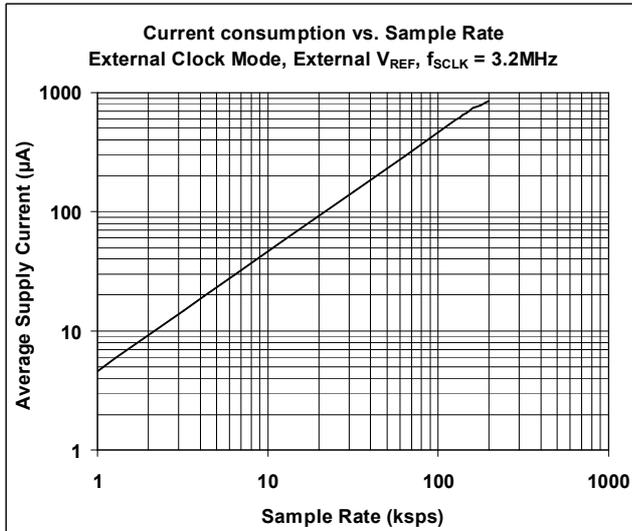
The average current consumption of the device depends very much on the sampling frequency and the type of protocol used to communicate with the device.

In order to achieve the lowest power consumption at low sampling frequencies, it is suggested to keep the conversion clock frequency at the maximum level of 3.2MHz and to power down the device between consecutive conversions. Figure 18 shows the characteristic current consumption of the ZADCS12x2 family with external reference supply versus Sampling Rate

3 Layout

To achieve optimum conversion performance care must be taken in design and layout of the application board. It is highly recommended to use printed circuit boards instead of wire wrap designs and to establish a single point star connection ground system towards AGND (see Figure 19).

Figure 18: Average Supply Current versus Sampling Rate



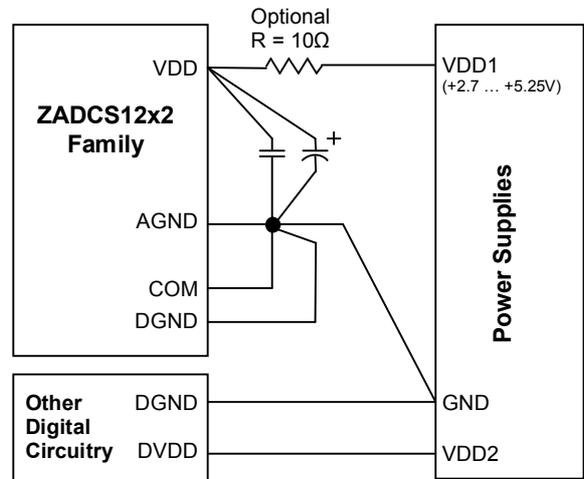
For optimal noise performance the star point should be located very close to the AGND pin of the converter. The ground return to the power supply should be as short as possible and low impedance.

All other analog ground points of external circuitry that is related to the A/D converter as well as the DGND pin of the device should be connected to this ground point too. Any other digital ground system should be kept apart as far as possible and connect on the power supply point only.

Analog and digital signal domains should also be separated as well as possible and analog input signals should be shielded by AGND ground planes from electromagnetic interferences. Four-layer PCB boards that allow smaller vertical distances between the ground plane and the shielded signals do generally show a better performance than two-layer boards.

The sampling phase is the most critical portion of the overall conversion timing for signal distortion. If possible, the switching of any high power devices or nearby digital logic should be avoided during the sampling phase of the converter.

Figure 19: Optimal Power-Supply Grounding System



The fully differential internal architecture of the ZADCS12x2 family ensures very good suppression of power supply noise. Nevertheless, the SAR architecture is generally sensitive to glitches or sudden changes of the power supply that occur shortly before the latching of the comparator output. It is therefore recommended to bypass the power supply connection very close to the device with capacitors of 0.1µF (ceramic) and >1µF (electrolytic).

In case of a noisy supply, an additional series resistor of 5 to 10 ohms can be used to low-pass filter the supply voltage.

The reference voltage should always be bypassed with capacitors of 0.1µF (ceramic) and ≥ 4.7µF (electrolytic) as close as possible to the VREF pin. If VREF is provided by an external source, any series resistance in the VREF supply path can cause a gain error of the converter. During conversion, a DC current of about 100µA is drawn through the VREF pin that could cause a noticeable voltage drop across the resistance.

4 Package Drawing

ZADCS1282 devices are delivered in a 20-pin SSOP-package that has the dimensions as shown in Figure 20 and Table 9. ZADCS1242 and ZADCS1222 devices apply respective 16-pin and 14-pin SSOP-packages. Their dimensions are specified in Table 10 and Table 11.

Figure 20: Package Outline Dimensions

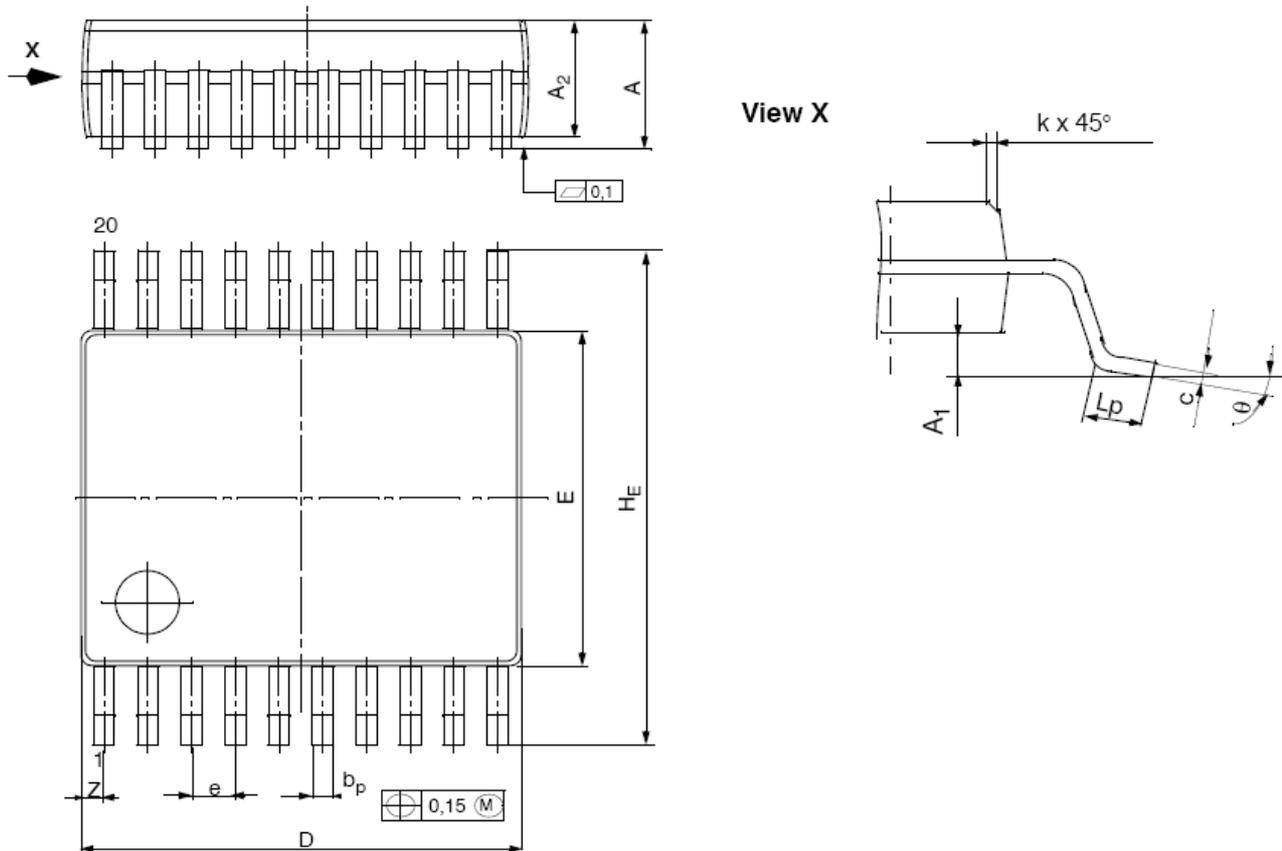


Table 9: Package Dimensions for ZADC1282 devices (mm)

Symbol	A	A ₁	A ₂	b _P	c	D	E	e _{nom}	H _E	L _P	Z	k	Θ	
Nominal	1.86	0.13	1.73	0.30	0.15	7.20	5.30	0.65	7.80				4°	
Maximum	1.99	0.21	1.78	0.38	0.20	7.33	5.38		7.90		0.74			8°
Minimum	1.73	0.05	1.68	0.25	0.09	7.07	5.20		7.65	0.63			0.25	0°

Table 10: Package Dimensions for ZADC1242 devices (mm)

Symbol	A	A ₁	A ₂	b _P	c	D	E	e _{nom}	H _E	L _P	Z	k	Θ	
Nominal	1.86	0.13	1.73	0.30	0.15	6.20	5.30	0.65	7.80				4°	
Maximum	1.99	0.21	1.78	0.38	0.20	6.07	5.38		7.90		0.89			10°
Minimum	1.73	0.05	1.68	0.25	0.09	6.33	5.20		7.65	0.63			0.25	0°

Table 11: Package Dimensions for ZADC1222 devices (mm)

Symbol	A	A ₁	A ₂	b _P	c	D	E	e _{nom}	H _E	L _P	Z	k	Θ	
Nominal	1.86	0.13	1.73	0.30	0.15	6.20	5.30	0.65	7.80				4°	
Maximum	1.99	0.21	1.78	0.38	0.20	6.33	5.38		7.90		1.22			10°
Minimum	1.73	0.05	1.68	0.25	0.09	6.07	5.20		7.65	0.63			0.25	0°

5 Ordering Information

Order Code	Resolution [Bit]	Channels [number]	Sample Rate [ksps]	Temperature range [°C]	QC 100 Qualified	Internal V _{ref}	INL	DNL	Pins [number]	Package [Type]	packing
ZADCS1282VIS20T	12	8	200	-25°C to +85°C	--	✓	± 1 LSB	± 1 LSB	20	SSOP	Tube
ZADCS1282IS20T	12	8	200	-25°C to +85°C	--	--	± 1 LSB	± 1 LSB	20	SSOP	Tube
ZADCS1242VIS16T	12	4	200	-25°C to +85°C	--	✓	± 1 LSB	± 1 LSB	16	SSOP	Tube
ZADCS1242IS16T	12	4	200	-25°C to +85°C	--	--	± 1 LSB	± 1 LSB	16	SSOP	Tube
ZADCS1222VIS14T	12	2	200	-25°C to +85°C	--	✓	± 1 LSB	± 1 LSB	14	SSOP	Tube
ZADCS1222IS14T	12	2	200	-25°C to +85°C	--	--	± 1 LSB	± 1 LSB	14	SSOP	Tube
ZADCS1282VQS20T	12	8	200	-40°C to +125°C	✓	✓	± 1 LSB	± 1 LSB	20	SSOP	Tube
ZADCS1282QS20T	12	8	200	-40°C to +125°C	✓	--	± 1 LSB	± 1 LSB	20	SSOP	Tube
ZADCS1242VQS16T	12	4	200	-40°C to +125°C	✓	✓	± 1 LSB	± 1 LSB	16	SSOP	Tube
ZADCS1242QS16T	12	4	200	-40°C to +125°C	✓	--	± 1 LSB	± 1 LSB	16	SSOP	Tube
ZADCS1222VQS14T	12	2	200	-40°C to +125°C	✓	✓	± 1 LSB	± 1 LSB	14	SSOP	Tube
ZADCS1222QS14T	12	2	200	-40°C to +125°C	✓	--	± 1 LSB	± 1 LSB	14	SSOP	Tube

6 ZMD Distribution Partner

ZMD ADC products as well as the ZADCS1282 Starterkit can be purchased from RUTRONIK Elektronische Bauelemente GmbH.

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